# **Rear window heating timer**

### Description

The window heating timers are bipolar integrated circuits. Due to time controlled functions, they reduce the current consumptions of high loads i.e., heating resistors. An

### Features

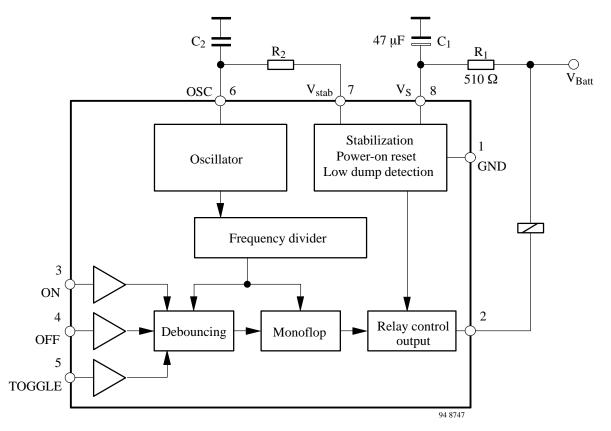
- Delay time range: 3.7 s to 20 h
- RC oscillator determines switching characteristics
- Relay driver with Z-diode
- Debounced input for toggle switch
- Two debounced inputs: ON and OFF

### Cases:

DIP 8	U 6046 B, U 6047 B
SO 8	U 6046 B–FP, U 6047 B–FP

ON-relay can be switched off after a preset delay time. The relay time can be interrupted manually whereas a retrigger function is not provided.

- Load dump protection
- RF interference protected
- Protection according to ISO/TR7637-1 (VDE 0839)
- U 6046 B: Inputs switched to V<sub>Batt</sub>
- U 6047 B: Inputs switched to ground





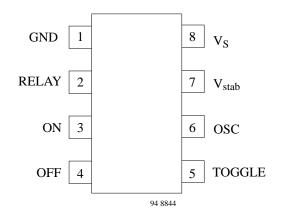
# U 6046 B / U 6047 B

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### **Pin Configuration**

Pin	Symbol	Function
1	GND	Reference point, ground
2	RELAY	Relay control output
3	ON	Switch-on input
4	OFF	Switch-off input
5	TOGGLE	Toggle input
6	OSC	RC oscillator input
7	V <sub>stab</sub>	Stabilized voltage
8	Vs	Supply voltage



# **Functional description**

#### Power supply, Pin 8

For reasons of interference protection and surge immunity, the supply voltage (Pin 8) must be provided with an RC circuit as shown in figure 2a. Dropper resistor,  $R_1$ , limits the current in case of overvoltage, whereas  $C_1$  smoothes the supply voltage at Pin 8.

Recommended values are:  $R_1 = 510 \Omega$ ,  $C_1 = 47 \mu F$ .

The integrated Z-diode (14 V) protects the supply voltage,  $V_S$ , therefore, the operation of the IC is possible between 6 V and 16 V, supplied by  $V_{Batt}$ .

However, it is possible to operate the integrated circuit with a 5 V supply, but it should be free of interference voltages. In this case, Pin 7 is connected to Pin 8 as shown in figure 2b, and the  $R_1C_1$  circuit is omitted.

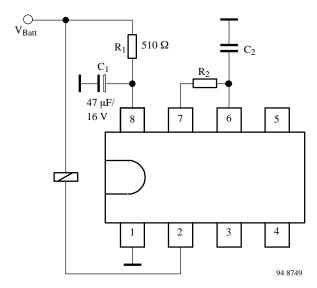


Figure 2a Basic circuit for 12 V supply and oscillator

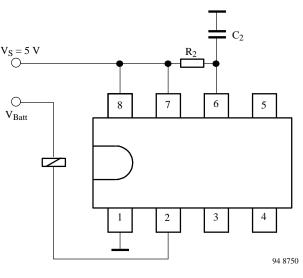


Figure 2b Basic circuit for  $V_S = 5 V$ 

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#### **Oscillator, Pin 6**

Oscillator frequency, f, is determined mainly by the  $R_2C_2$  circuit. Resistance,  $R_2$ , determines the charge time, and the integrated resistance (2 k $\Omega$ ) is responsible for discharge time. For the stability of the oscillator frequency, it is recommended that the selected  $R_2$  value be much greater than the internal resistance (2 k $\Omega$ ), because the temperature response and the tolerances of the integrated resistance are considerably greater than the external resistance value.

Oscillator frequency, f, is calculated as follows:

 $f = \frac{1}{t_1 + t_2}$ 

where

 $\begin{array}{l} t_1 = charge \ time = \alpha_1 \cdot R_2 \cdot C_2 \\ t_2 = discharge \ time = \alpha_2 \cdot 2 \ k\Omega \ \cdot \ C_2 \end{array}$ 

 $\alpha_1$  and  $\alpha_2$  are constants as such  $\alpha_1 = 0.833$  and  $\alpha_2 = 1.551$  when  $C_2 = 470$  pF to 10 nF  $\alpha_1 = 0.746$  and  $\alpha_2 = 1.284$  when  $C_2 = 10$  nF to 4700 nF

Debounce time,  $t_3$ , and the delay time,  $t_d$ , depend on the oscillator frequency, f, as follows:

$$t_3 = 6 \cdot \frac{1}{f}$$
$$t_d = 73728 \cdot \frac{1}{f}$$

Table 1 shows relationships between  $t_3$ ,  $t_d$ ,  $C_2$ ,  $R_2$  and frequencies from 1 Hz to 20 kHz.

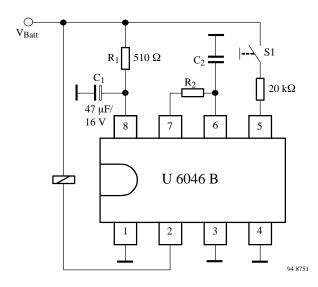


Figure 3a TOGGLE function U 6046 B

#### **Relay control output**

The relay control output is an open collector Darlington circuit with an integrated 23-V Z-diode for limitation of the inductive cut-off pulse of the relay coil. The maximum static collector current must not exceed 300 mA and saturation voltage is typically 1.1 V @ 200 mA.

#### Interference voltages and load dump

The IC supply is protected by  $R_1$ ,  $C_1$ , and an integrated Z-diode, while the inputs are protected by a series resistor, integrated Z-diode and RF capacitor (refer to Figure 6).

The relay control output is protected via the integrated 23-V Z-diode in the case of short interference peaks. It is switched to conductive condition for a battery voltage of greater than approx. 40 V in the case of load dump. The output transistor is dimensioned so that it can withstand the current produced.

#### **Power-on reset**

When the operating voltage is switched on, an internal power-on reset pulse (POR) is generated which sets the logic of the circuits to a defined initial condition. The relay output is disabled.

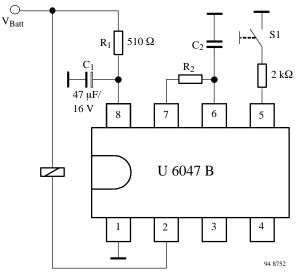


Figure 3b TOGGLE function U 6047 B

### Relay control output behaviour, Pin 2

Time functions (relay output) can be started or interrupted by the three inputs i.e., ON, OFF or TOGGLE (Pins 3, 4 and 5).

The relay becomes active if the time function is triggered, and the relay contact is interrupted after the elapse of delay time,  $t_d$ . There are two input possibilities:

## Toggle input, figure 3 and 5A

When the push-button (TOGGLE) switch,  $S_1$ , is pressed for the first time, the relay becomes active after the debounce time,  $t_3$ , i.e., the relay output, Pin 2, is active.

Renewed operation of  $S_1$  causes the interruption of the relay contact and the relay is disabled. Each operation of the toggle switch,  $S_1$ , changes (alters) the condition of the relay output when the debounce time,  $t_3$ , is exceeded i.e., the TOGGLE function.

If the relay output is not disabled by pressing the switch  $S_1$ , the output is active until the delay time,  $t_d$ , is over.

# ON, OFF inputs, Pins 3 and 4, figures 4 and 5B

To avoid simultaneous operation of both inputs, Pin 3 (ON) and Pin 4 (OFF), use of two-way contact with centre-off position with spring returns (also known as rocker-actuated switch) is recommended.

Pressing the push-button switch (Pin 3-ON) leads to the activation of the relay after the debounce time,  $t_3$ , whereas

the switching of the Pin 4 switch correspondingly leads to the relay being de-energized. If the relay is not de-energized by the push-button switch, it becomes disabled after the delay time,  $t_d$ , is over.

Combined operation, "TOGGLE and ON/OFF" is not possible due to the fact that there is only one debouncing circuit. Debouncing functions on both sides i.e., whenever  $S_1$  is ON or OFF.

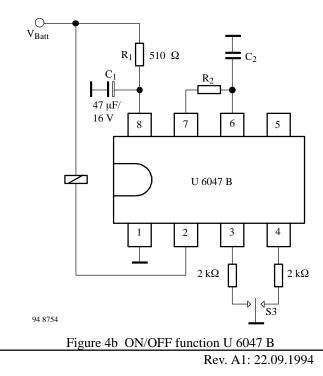
If Pin 3 (input ON) is continuously closed, the delay time,  $t_d$ , still elapses and the relay is interrupted. This can be used to generate a defined power-on-reset pulse to trigger, for example, a delay time,  $t_d$ , when the battery voltage,  $V_{Batt}$ , is applied.

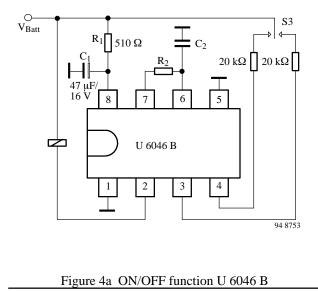
Figure 6a shows the input circuit of U 6046 B. It has an integrated pull-down resistance (20 k $\Omega$ ), RF capacitor (15 pF) and Z-diode (7 V). It reacts to voltages greater than 2 V. The external protective resistor has a value of 20 k $\Omega$  and the push-button switch, S, is connected to the battery as shown in the diagram.

Contact current, I, is calculated as follows:

$$I = \frac{V_{Batt} - V_Z}{R(= 20 \text{ k}\Omega)} \text{ where } V_{Batt} = 12 \text{ V}, V_Z = 7 \text{ V}$$
$$I = \frac{(12-7) \text{ V}}{20 \text{ k}\Omega} \approx 0.25 \text{ mA}$$

It can be increased by connecting a 5.6 k $\Omega$  resistor from the push-button switch to ground as shown in figure 10a.





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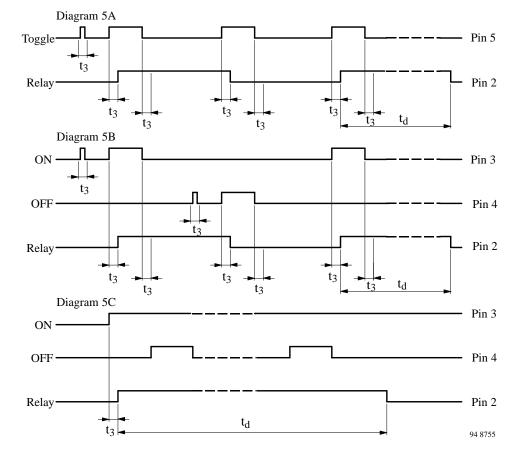
Figure 6b shows the input circuit of U 6047 B. It has an integrated pull-up resistance (100 k $\Omega$ ), RF capacitor (15 PF) and Z-diode (7 V). The circuit reacts to voltages less than 2 V. The external protective resistance has a value of 2 k $\Omega$  and the push-button switch is connected to GND. Contact current, I, is calculated as follows:

$$I \approx \frac{V_s}{(100 \text{ k}\Omega + 2 \text{ k}\Omega)}$$
 when  $V_{Batt} = 12 \text{ V}$   
 $I \approx 0.1 \text{ mA}$ 

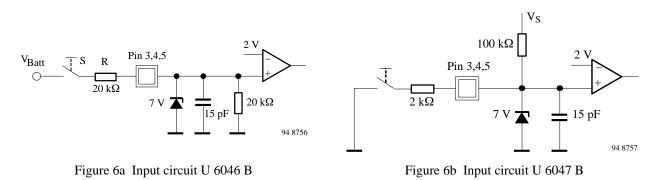
### **Timing waveform**

It can be increased by connecting a 5.6 k $\Omega$  resistor from the push-button-switch to V<sub>Batt</sub> as shown in figure 10b.

The connecting diodes prevent the current flow to the input of the Z-diodes when the rocker actuated-switch is in open-state (current-consumption only in standby-mode). If necessary these diodes can be omitted.



#### Figure 5 Behaviour of the relay control output as a function of input condition



# **Absolute Maximum Ratings**

Parameters	Symbol	Value	Unit
Operating voltage, static, 5 min	V <sub>Batt</sub>	24	V
Ambient temperature range	T <sub>amb</sub>	-40 to +125	°C
Storage temperature range	T <sub>stg</sub>	-55 to +125	°C
Junction temperature	Tj	150	°C

# **Thermal Resistance**

	Parameters	Symbol	Maximum	Unit
Junction ambient	DIP 8	T <sub>thJA</sub>	110	K/W
	SO 8	T <sub>thJA</sub>	160	K/W

# **Electrical Characteristics**

$V_{Batt} = 13.5 \text{ V}, T_{amb} = 25^{\circ}\text{C}$ , reference point ground, figure	2, unless otherwise specified
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Parameters	Test Conditions / Pin	Symbol	Min	Тур	Max	Unit
Operating voltage	$R_1 \ge 510 \Omega$ t < 5 min t < 60 min	V <sub>Batt</sub>	6		16 24 18	v
5 V supply	Without $R_1, C_1$ figure 2bPins 7 and 8	V <sub>8</sub> , V <sub>7</sub>	4.3		6.0	V
Stabilized voltage	$V_{Batt} = 12 V$ Pin 7	V <sub>7</sub>	5.0	5.2	5.4	V
Undervoltage threshold	Power on reset	Vs	3.0		4.2	V
Supply current	All pushbuttons open, Pin 8	IS		1.3	2.0	mA
Internal Z-diode	$I_8 = 10 \text{ mA}$ Pin 8	VZ	13.5	14	16	V
Relay control output	Pin 2					
Saturation voltage	$I_2 = 200 \text{ mA}$ $I_2 = 300 \text{ mA}$	V <sub>2</sub>		1.2	1.5	V
Leakage current	$V_2 = 14 V$	I <sub>lkg</sub>		2	100	μΑ
Output current		I <sub>2</sub>			300	mA
Output pulse current						
Load dump pulse	$t \le 300 \text{ ms}$	I <sub>2</sub>			1.5	A
Internal Z-diode	$I_2 = 10 \text{ mA}$	VZ	20	22	24	V
Oscillator input	f = 0.001 to 40 kHz, see table 1	Pin 6				
Internal discharge resistance	$V_6 = 5 V$	R <sub>6</sub>	1.6	2.0	2.4	kΩ
Switching voltage	Lower Upper	V <sub>6L</sub> V <sub>6H</sub>	0.9 2.8	1.1 3.1	1.4 3.5	V
Input current	$V_6 = 0 V$	-I <sub>6</sub>			1	μΑ
Switching times	· ·					
Debounce time		t3	5		7	cycles
Delay time		t <sub>d</sub>	72704		74752	cycles
Inputs ON, OFF, TOGG	LE Pins 3, 4 and 5					1
Switching threshold voltage	je	V <sub>3,4,5</sub>	1.6	2.0	2.4	V
Internal Z-diode	$I_{3, 4, 5} = 10 \text{ mA}$	VZ	6.5	7.1	8.0	V
Pull-down resistance	$V_{3,4,5} = 5 V$ U 6046 B	R <sub>3,4,5</sub>	13	20	50	kΩ
Pull-up resistance	$V_{3,4,5} = 0 V$ U 6047 B	R <sub>3,4,5</sub>	70	100	140	kΩ

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Frequency f	Debounce time t <sub>3</sub>	Delay t		C <sub>2</sub>	R <sub>2</sub>	Frequency f <sub>0</sub>	Debounce time t <sub>3</sub>	Delay t	/ time d	C <sub>2</sub>	R <sub>2</sub>
Hz	ms	min	S	nF	kΩ	Hz	ms	min	s	nF	kΩ
1	6000	1229		4700	280	700	9		105	10	170
2	3000	614		1000	650	800	8		92	10	150
3	2000	410		1000	440	900	7		82	10	130
4	1500	307		1000	330	1000	6		74	10	120
5	1200	246		1000	260	2000	3.00		37	1	600
6	1000	205		1000	220	3000	2.00		25	1	400
7	857	176		1000	190	4000	1.50		18	1	300
8	750	154		1000	160	5000	1.20		15	1	240
9	667	137		1000	140	6000	1.00		12	1	200
10	600	123		1000	130	7000	.86		11	1	170
20	300	61		100	650	8000	.75		9	1	150
30	200	41		100	440	9000	.67		8	1	130
40	150	31		100	330	10000	.60		7	1	120
50	120	25		100	260	11000	.55		6.7	1	110
60	100	20		100	220	12000	.50		6.1	1	99
70	86	18		100	190	13000	.46		5.7	1	91
80	75	15		100	160	14000	.43		5.3	1	85
90	67	14		100	140	15000	.40		4.9	1	79
100	60	12		100	130	16000	.38		4.6	1	74
200	30		369	10	600	17000	.35		4.3	1	70
300	20		246	10	400	18000	.33		4.1	1	66
400	15		184	10	300	19000	.32		3.9	1	62
500	12		147	10	240	20000	.30		3.7	1	59
600	10		123	10	200						

#### Table 1 Oscillator frequency, debounce time, delay time. dimensioning

# U 6046 B / U 6047 B

# **3.** Applications

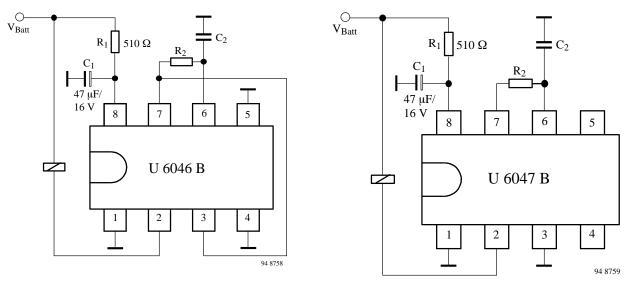
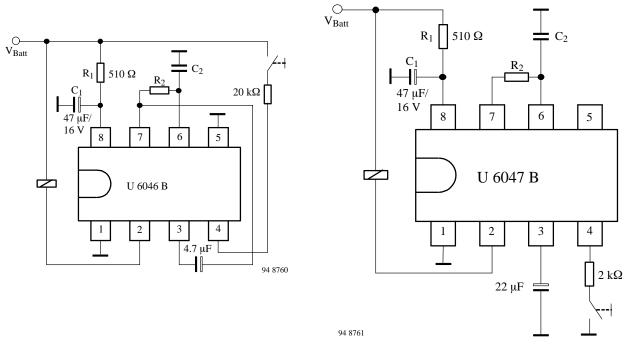
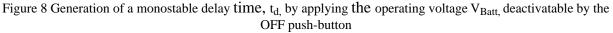


Figure 7 Generation of a monostable delay time, t<sub>d</sub>, caused by applying the operating voltage V<sub>Batt</sub>, not externally deactivatable.





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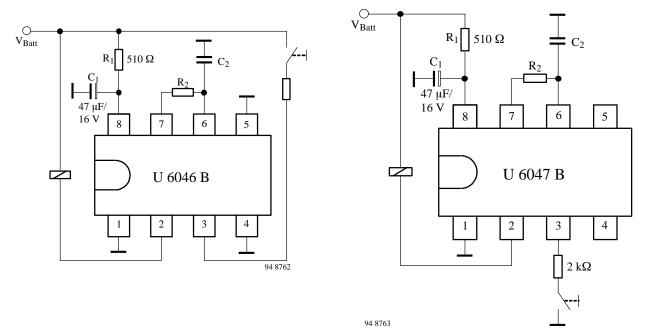


Figure 9 Monostable delay time, t<sub>d</sub>, can be activated by the ON push-button, not externally deactivatable

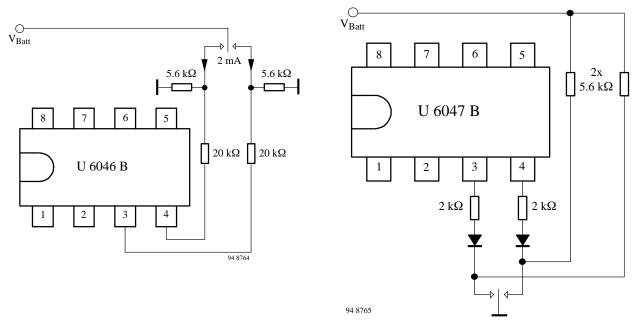


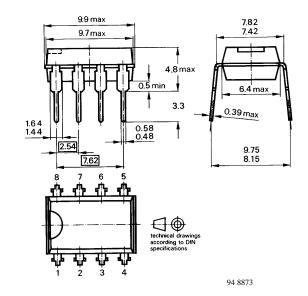
Figure 10 Increasing the contact current by parallel resistors

# U 6046 B / U 6047 B

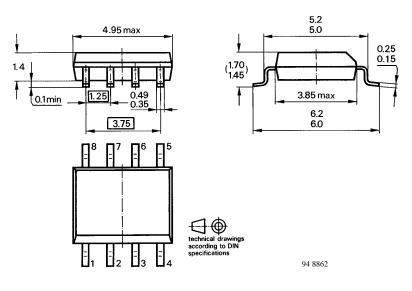
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### **Dimensions in mm**

Package: DIP 8



Package: SO 8



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